
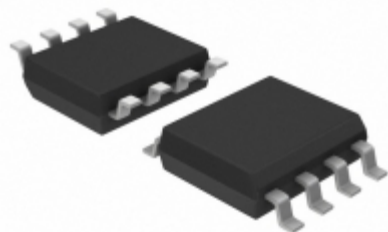

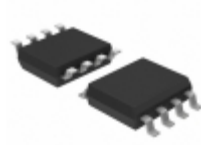
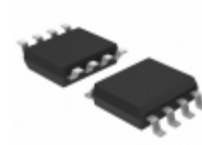
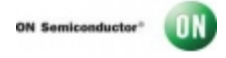


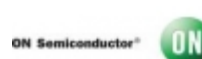

	<h2>NTMS4873NFR2G</h2>
	<p>Hersteller-Teilenummer: NTMS4873NFR2G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 7.1A 8-SOIC</p> <p>Datenblätter:  NTMS4873NFR2G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 29639 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMS4873NFR2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 7.1A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	29639 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	870mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.1A (Ta)
Rds On (Max) @ Id, Vgs	12 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1900pF @ 15V
Verpackung	Tape & Reel (TR)

























NTMS4873NFR2G ist neu im Original, Suche NTMS4873NFR2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMS4873NFR2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMS4873NFR2G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMS4916UT001 ON NTMS4916UT001 ON</p>	 <p>NTMS4872NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p>	 <p>NTMS4916NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11.4A SO8FL</p>	 <p>NTMS4816N AMI Semiconductor / ON Semiconductor NTMS4816N ON</p>
 <p>NTMS4840NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 4.5A 8SOIC</p>	 <p>NTMS4816NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6.8A 8-SOIC</p>	 <p>NTMS4916N AMI Semiconductor / ON Semiconductor NTMS4916N ON</p>	 <p>NTMS4816NG ON NTMS4816NG ON</p>

heiße Teile

Mehr

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|---|---|---|--|--|
|  NTMS4101PR2G |  NTMS4105NR2G |  NTMS4107NR2G |  NTMS4176PR2G |  NTMS4177P |
|  NTMS4177PR2G |  NTMS4404NR2G |  NTMS4503NR2G |  NTMS4700NR |  NTMS4700NR2G |
|  NTMS4704NR2G |  NTMS4705NR2G |  NTMS4706NR2G |  NTMS4800NR2G |  NTMS4801N |
|  NTMS4801NR2G |  NTMS4802N |  NTMS4802NR2G |  NTMS4807N |  NTMS4807NR2G |
|  NTMS4816N |  NTMS4816NG |  NTMS4816NR2G |  NTMS4840NR2G |  NTMS4872NR2G |
|  NTMS4916AS001 |  NTMS4916N |  NTMS4916NR2G |  NTMS4916UT001 |  NTMS4917NR2G |
|  NTMS4917UT001 |  NTMS4920N |  NTMS4920NR2G |  NTMS4937N |  NTMS4937NR2G |
|  NTMS4939N |  NTMS4939NR2G |  NTMS4N01R2 |  NTMS4P01R2G |  NTMS5835NL |
|  NTMS5835NLR2G |  NTMS5838NLR2G |  NTMS5P02 |  NTMS5P02R2 |  NTMS5P02R2G |
|  NTMS7N03R2 |  NTMS7N03R2G |  NTMS7N03R2R2G |  NTMSD2P102LR2 |  NTMSD2P102R2 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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